Radiation induced oscillations of the Hall resistivity in two-dimensional electron systems

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We consider the e ect of m icrowave radiation on the Hall resistivity in two-dimension electron systems. It is shown that photon-assisted impurity scattering of electrons can result in oscillatory dependences of both dissipative and Hall components of the conductivity and resistivity tensors on the ratio of radiation frequency to cyclotron frequency. The Hall resistivity can include a component induced by m icrowave radiation which is an even function of the magnetic eld. The phase of the dissipative resistivity oscillations and the polarization dependence of their amplitude are compared with those of the Hall resistivity oscillations. The developed m odel can clarify the results of recent experimental observations of the radiation induced Halle ect.

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The oscillatory dependence of the conductivity of twodim ensional electron system s (2D E S's) under m icrow ave radiation in a magnetic eld on the ratio of radiation freto cyclotron frequency c has been predicted quencv m ore than three decades ago by the author [1] (see also Ref. [2]). As shown [1, 2], the variation of the dissipative conductivity caused by irradiation (m icrow ave photo conductivity) is negative if som ew hat exceeds ~/ = 1;2;3; ... In this situation, the net dissiwhere pative conductivity can become negative if the incident microwave power is su ciently high (e ect of absolute negative conductivity or ANC). The oscillations of the dissipative components of the conductivity tensor xx and vy considered in Refs. [1, 2] are associated with photon-assisted in purity scattering of electrons accom panied by their transitions between the Landau levels (LL's). As shown in Refs. [3, 4, 5, 6], photon-assisted in purity scattering can result in variations of the Hall conductivity components xy and yx (with $xy \in$ vx due to an even dependence of such variations on the magnetic eld). The oscillatory dependences of the dissipative conductivity in a 2DES as a function of $=_{c}$ were observed experim entally by Zudov et al. [7] and Ye et al. [8]. Shortly thereafter M ani et al. [9] and Zudov et al. [10] observed vanishing electrical resistance R_{xx} (R_{xx} / x_{x} = x_{xx} = ($^{2}_{xx}$ + $^{2}_{xy}$) with increasing m icrowave power and form ation of the so-called zeroresistance states. This e ect is attributed to reaching of the threshold of ANC [5, 6, 11, 12, 13] associated with the mechanism considered in Refs. [1, 2]. The feasibility of the latter is ow ing to high electron m obility in the 2D E S's studied, so that the cyclotron resonance and its harm onics can be observed at rather sm all m agnetic elds and, hence, at m icrow ave frequencies about 100 G H z and less. Since the microw ave power required for ANC is approxim ately proportional to ³, m icrow ave sources with m oderate powers can be used at moderate magnetic elds. Further experim ental results related to the oscillations of m icrow ave photoconductivity and their consequences below and above the ANC threshold are presented in Refs. [14, 15, 16, 17, 18, 19]. In particular, Studenikin, et

al. [18] and M ani, et al. [19] dem onstrated the oscillations of the H all resistance R_{xy} which is related to the conductivity components as $R_{xy} / xy = xy = (\frac{2}{xx} + \frac{2}{xy})$. One can assume that the origin of these oscillations is analogous to that discussed previously [3, 4, 5, 6].

In this paper, we calculate the dependences of $_{\rm xx}$ and xy vs c= using a model invoking photon-assisted im purity scattering of electrons as the main mechanism determ ining the microwave photoconductivity. The model under consideration generalizes that of R efs. [3, 4] in line with our recent papers [20, 21]. In principle, the concept based on photon-assisted in purity scattering as the main mechanism responsible for the observed microwave photo conductivity explains virtually all features of the e ect, although it is prematurely to draw the nal conclusions yet. Namely, the positions of the photoconductivity zeros, maxima, and minima [1, 2, 5, 6], saturation of the oscillation m agnitude with increasing m icrow ave power and, hence, relatively large m agnitude of m axim a and minim a corresponding to the cyclotron resonance harmonics [20, 22]. A signi cant sensitivity of the amplitude of the m icrow ave photoconductivity oscillations to the tem perature can be attributed to the contribution of photon-assisted acoustic phonon scattering [21, 23] and an increase of the LL broadening due to increasing dependence of the electron-electron and acoustic scattering on the tem perature (see, for example, Refs. [24] and [25], respectively). The experim ental observation of ANC [26] associated with photon-assisted electron transitions between spatially separated states in the neighboring quantum wells (microwave hopping photoconductivity associated with similar transitions between impurity states was analyzed in Ref. [27]) is a strong argument in favor of the dynamical mechanism of ANC in 2DES's. Generally, the e ect of ANC in a 2DES 28, 29] and in a 3DES [30, 31, 32] subjected to a magnetic eld can also be associated with a deviation of the electron distribution function from equilibrium one. Dorozhkin [17] proposed a model based on the assumption that the electron distribution function is nonmonotonic with inversion population of the states near the center of LL's caused by the ab-

sorption of m icrowave radiation. In this m odel, the electron Larm or orbit centers hop along the dc electric eld (contributing to the dissipative conductivity) both im m ediately absorbing m icrow ave photons (absorption due to the photon-assisted in purity scattering) and ow ing to nonradiative in purity scattering upon excitation. If the m axim a of the electron density of states are shifted with respect to the maxim a of the distribution function, im purity scattering can, as shown by E lesin [30], lead to ANC. The main problem, however, is to realize such nontrivial electron distributions. Recently, Dm itriev, et al. [33] developed a similar model applied to 2DES's irradiated with microwaves in which, as assumed, the electron distribution function can be oscillatory. In this regard, the consideration of the e ect of m icrow ave radiation on the Hall conductivity is crucial to clarify genuine origin of the experim ental results [7, 8, 9, 10, 14, 15, 16, 17, 18, 19].

The probability of the electron transition between the $(N; k_x; k_y)$ and $(N^0; k_x + q_x; k_y + q_y)$ states in the presence of the net dc electric eld E = (E; 0; 0) (including both the applied and H all components) perpendicular to the magnetic eld H = (0; 0; H) and the ac microwave eld $E = (Ee_x; Ee_y; 0)$ polarized in the 2DES plane (e_x and e_y are the components of the microwave eld complex polarization vector), is given by the following formula obtained on the base of the interaction representation of the operator of current via solutions of the classical equations of electron motion [3, 4, 20]:

$$W_{N;k_{x};k_{y};N^{0};k_{x}+q_{x};k_{y}+q_{y}} = \frac{2 N_{i}}{2} \frac{X}{M} \int_{M} \mathcal{Y}_{q} \mathcal{J}_{N;N^{0}} (L^{2}q^{2}=2) \mathcal{J}_{M}$$

$$J_{M}^{2}$$
 ($(q_{x};q_{y})$) $M \sim + (N N^{0}) \sim _{c} + eE L^{2}q_{y}$]: (1)

Here N is the LL index, k_x and k_y are the electron quantum numbers, q_x and q_y are their variations due to photon-assisted in purity scattering, $q = \frac{q_x^2 + q_y^2}{q_x^2 + q_y^2}$, e = jej is the electron charge, ~ is the Planck constant, M is the number of absorbed or emitted real

m icrowave photons, N i is the impurity concentration, V_g is the matrix element of the electron-impurity interaction, and $Q_{N;N} \circ () / L_N^{(N^{\circ} N)} () \exp($ =2), where L_{N} () is the Laguerre polynom ial. The LL form -factor is determined by the function characterized by the LL broadening . The e ect of microwave radiation is reduced to the inclusion of the energy M ~ of really absorbed or emitted M photons in the argument of the function in Eq. (1) and the appearance of the Bessel functions J_M ($(q_x;q_y)$) [3, 4]. Here $(q_x;q_y) =$ $e j \mathbf{g}_{\mathbf{x}} \mathbf{e}_{\mathbf{x}} + \mathbf{g}_{\mathbf{y}} \mathbf{e}_{\mathbf{y}} \quad \mathbf{i} (c =) (\mathbf{g}_{\mathbf{x}} \mathbf{e}_{\mathbf{y}} - \mathbf{g}_{\mathbf{e}_{\mathbf{x}}}) \mathbf{j}, \text{ is proportional}$ (+ i)j j²_c m to the amplitude of the electron orbit center oscillation in the acm icrowave eld (limited by the dephasing of the electron motion), where m is the electron e ective mass. The quantity $(q_x;q_y)$ depends on the polarization properties of the incident radiation. At su ciently high m icrow ave power, the am plitude of the electron orbit center oscillation in the microwave eld can become about the quantum Larm or radius L.

In the absence of microw ave irradiation at moderate dc $E_c = \sim c = eL$, the probability of interelectric eldsE LL transitions is very small. In this case, such transitions provide an exponentially sm all contribution to the electron dissipative conductivity [34]. At E . $E_b = \sim =eL$, the electron dissipative conductivity is due to electron scattering processes associated with the intra-LL transitions [35]. W hen a 2DES is irradiated with m icrowaves, the variation of the dissipative conductivity (m icrow ave photoconductivity) can be associated with both alteration of the intra-LL scattering (that can, in particular, result in the e ect of dynam ic localization 26]) and appearance of the photon-assisted transitions between LL's. Considering Eq. (1), the contribution to the dissipative current j_0 (along the axis x) associated with the photon-induced inter-LL transitions and the variation of the Hall current due to the scattering processes in question j_{H} (along the axis y) can be presented as

$$\dot{\mathbf{j}}_{\mathrm{b}} = \frac{\mathrm{eN}_{\mathrm{i}}}{\sim} \frac{X}{M_{\mathrm{i}}N_{\mathrm{i}}N^{\mathrm{o}}} \mathbf{f}_{\mathrm{N}} \left(\mathbf{1} - \mathbf{f}_{\mathrm{N}}^{\mathrm{o}}\right) \frac{Z}{d^{2}q \, q_{\mathrm{y}} \, \mathbf{y}_{\mathrm{q}} \, \mathbf{j}^{2} \, \mathbf{D}_{\mathrm{N},\mathrm{i}} \circ (\mathbf{L}^{2} q^{2} = 2) \, \mathbf{j}^{2} \mathbf{J}_{\mathrm{M}}^{2} \left(-(\mathbf{q}_{\mathrm{x}};\mathbf{q}_{\mathrm{y}})\right) \mathbf{M} \sim + (\mathbf{N} - \mathbf{N}^{0}) \sim _{\mathrm{c}} + \mathrm{eE} \, \mathbf{L}^{2} \mathbf{q}_{\mathrm{y}} \, \mathbf{j} \mathbf{q}; (2)$$

$$\dot{\mathbf{j}}_{\mathrm{H}} = \frac{\mathrm{eN}_{\mathrm{i}}}{\sim} \frac{X}{M_{\mathrm{i}}N_{\mathrm{i}}N^{\mathrm{i}}} \mathbf{f}_{\mathrm{N}} \left(\mathbf{1} - \mathbf{f}_{\mathrm{N}}^{\mathrm{i}}\right) \frac{Z}{d^{2}q \, \mathbf{q}_{\mathrm{x}} \, \mathbf{j}_{\mathrm{q}} \, \mathbf{j}^{2} \, \mathbf{D}_{\mathrm{N},\mathrm{i}} \circ (\mathbf{L}^{2} q^{2} = 2) \, \mathbf{j}^{2} \mathbf{J}_{\mathrm{M}}^{2} \left(-(\mathbf{q}_{\mathrm{x}};\mathbf{q}_{\mathrm{y}})\right) \mathbf{M} \sim + (\mathbf{N} - \mathbf{N}^{0}) \sim _{\mathrm{c}} + \mathrm{eE} \, \mathbf{L}^{2} \mathbf{q}_{\mathrm{y}} \, \mathbf{j}; (3)$$

Here, f_N is the lling factor of the N th Landau level given by the Ferm i distribution function. A ssum ing for de niteness that the LL density of states is Lorentzian

with the LL-broadening $< ;_{c}$, at su ciently small dc electric elds E $E_{b} < E_{c}$, and ac microwave elds $(q_{x};q_{y})$ 1, for the quantities $_{D} = j_{D} = E$ and

 $_{\rm H}$ = $j_{\rm H}$ =E from Eqs. (2) and (3), substituting the integration over d²q for the integration over qdqd , where sin = $q_{\rm H}$ =q, one can obtain

$$z_{2}$$

D / (1 e^{-=T}) d sin² C (;; c); (4)

$$_{\rm H}$$
 / (1 e $^{-{\rm T}}$) d sin cos C (;; c); (5)

where

C (P; ; ; c) = N iL
$$dqq^2 y_q f exp (f q^2=2)$$

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$$X = \frac{J_{M}^{2} (Lq^{P} \overline{P} f)}{[(c M^{2} + 2]^{2}]} (c M^{2}) (c M^{2})$$

Here T is the tem perature, = $P_{N} f_{N} (1 f_{N+}) = N$, P / cE^{2} is the m icrow ave power norm alized by p = (m ³=2) (where = $e^{2} = -c'$ 1=137 and c is the speed of light),

$$f(= _{c}) = \frac{(= _{c})[1 + (= _{c})^{2}]}{[1 - (= _{c})^{2}]^{2} + (= _{c})^{2}(= _{c})^{2}};$$

and () = $p_{2=[1 + (c^2)]je_x} \cos + e_y \sin i(c^2) e_y \cos e_y \sin j$. In deriving Eq. (6), it is assumed that m any LL's are occupied, so only the terms corresponding to the transitions between upper LL's are important, and, therefore, the matrix elements in the quasi-classical limit can be used.

Form ulas (4) - (6) describe the dissipative and Hall m icrow ave photoconductivities as functions of the normalized power ofm icrow ave radiation, its frequency and polarization, as well as the cyclotron frequency. In particular, these form ulas yield oscillatory dependences of ______ and _____ on = ___ and a nonlinear dependence of the amplitude on P. At = ____ & , the m icrow ave dissipative photoconductivity ______ < 0. In this case, the net dissipative conductivity can be also negative if the m icrow ave power is su ciently large. In the vicinity of the cyclotron resonance (______) atm oderate m icrow ave powers P . m in f ______ (= ___)^2, one can take into account that J_1^2 (Lq Pf) Pf) _____ qPf _____ and obtain

$$C(P; ; ; _{c}) / P^{2}() \frac{f(=_{c})(_{c})}{[(_{c} \frac{3}{2} + 2)^{2}]} S_{i};$$
 (7)

where $S_i = N_i {B_1 \atop 0} dqq^4 y_q f exp(L^2q^2=2)$. Using Eqs.(4), (5), and (7), we arrive at

with

$$\frac{1}{\left[\left(\begin{array}{c}c\\c\end{array}\right)^{2}+c\right]^{2}} \int \frac{f\left(\begin{array}{c}c\\c\end{array}\right)^{2}\left(\begin{array}{c}c\\c\end{array}\right)^{2}+c\right)^{2}} \int \frac{f\left(\begin{array}{c}c\\c\end{array}\right)^{2}}{\left[\left(\begin{array}{c}c\\c\end{array}\right)^{2}+c\right]^{2}} \int \frac{f\left(\begin{array}{c}c\\c\end{array}\right)^{2}}{\left[\left(\begin{array}{c}c\\c\end{array}\right)^{2}+c\right]^{2}} \int \frac{f\left(\begin{array}{c}c\\c\end{array}\right)^{2}}{\left(\begin{array}{c}c\\c\end{array}\right)^{2}} \int \frac{f\left(\begin{array}{c}c\\c\end{array}\right)$$

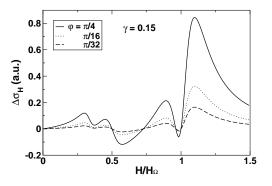


FIG.1: Magnetic eld dependencies of the Hallphotoconductivity at di erent polarization angles.

$$_{\rm D} = \frac{1}{2} \int_{0}^{Z_{2}} d \sin^{2} f(t); \qquad (10)$$

$$_{\rm H} = \frac{1}{2} \int_{0}^{Z_{2}} d\cos \sin^{2}(t)$$
: (11)

In the case of circular polarization, (') = 1 at any ratio = $_{\rm c}$ and, hence, $_{\rm D}$ = 1=2 and $_{\rm H}$ = 0. At a linear polarization of the ac microwave eld, introducing the angle between the directions of the dc and ac elds 'so that $e_x = \cos'$ and $e_y = \sin'$, we obtain

$$_{\rm D} = \frac{1}{4} + \frac{^2 + (\frac{2}{\rm c} - ^2)\sin^2 \prime}{2(\frac{2}{\rm c} + ^2)}; \qquad (12)$$

$$_{\rm H} = \frac{1}{4} \quad \frac{2}{c} \quad \frac{2}{c} + 2 \quad \sin 2' : \tag{13}$$

In the vicinity of the cyclotron resonance, Eqs. (10) and (11) yield $_{\rm D}$ ' 3=4 and $_{\rm H}$ ' ($_{\rm c}^2$ ') sin 2' =8 $_{\rm c}^2$. The obtained polarization dependences are consistent with the general symmetry properties of the photoconductivity tensor [36] as well as with the previous calculations [3, 4, 6, 37]. In particular, as follows from Eqs. (8) and (12), $_{\rm D}$ exhibits larger am plitude of oscillations at ' = =2 than at ' = 0 in agreement with the results of Ref. [6]. Equations (8), (12), and (13) show that the ratio of $_{\rm H}$ and $_{\rm D}$ at their maxim a and minim a corresponding to a cyclotron resonance harm onic is larger that this ration at the maxim um and minim um in the vicinity of the cyclotron resonance, where $_{\rm H}$ (= c) sin 2'.

The conductivity tensor components are related to $_{D}$ and $_{H}$ as $_{xx} = _{yy} = _{D} + _{D}$, $_{xy} = _{H} + _{H}$, and $_{yx} = _{H} + _{H}$, where $_{D}$ and $_{H}$ are the the dissipative and H all conductivities without microwave radiation. As follows from the above results, both $_{D}$ and $_{H}$ do not vary when the magnetic eld is reversed. This im plies that in the situation under consideration, $_{xy}$ and $_{yx}$ are not equal to each other.

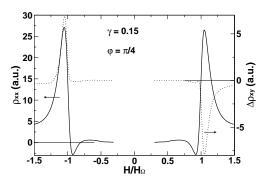


FIG. 2: M agnetic eld dependencies of the dissipative (solid curves) and H all (dotted curves) resistivities at ' = =4.

Expressing the components of the conductivity tensor via $_{D}$, $_{H}$, $_{D}$, and $_{H}$, taking into account that $_{H}$ $_{D}$; $_{D}$; $_{H}$, and using Eq. (8), the variation of the H all resistivity under the in uence of m icrowave radiation can presented in the following form :

$$x_{y}' \xrightarrow{H} \frac{2}{H} \xrightarrow{(2 D + D)} \frac{D}{H}$$

$$P \xrightarrow{-}{2}_{H} + \frac{(2 D + P - D)}{H} = (14)$$

Equation (14) qualitatively describes the following effects: (a) a shift of the $_{\rm xy}$ vs H dependence (presence of a component which is an odd function of the magnetic

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eld) stimulated by microwave radiation, (b) antisymmetric oscillations of $_{xy}$ with varying magnetic eld, and (c) markedly di erent span of $_{xy}$ at H & H and H . H , i.e., at > 0 and < 0 [18, 19]. As follows from Eq. (14), $_{xy}$ comprises a component (corresponding to the term proportional to $_{\rm H}$ / P $_{\rm H}$) which is an even function of the magnetic eld. A coording to Eqs. (13) and (14), this component essentially depends

on the polarization of microwave radiation. The term in Eq. (14) dependent on _D / P _D changes its sign when the magnetic eld reverses. Figure 1 shows the dependence of the Hallm icrow ave photoconductivity Н on the magnetic eld normalized by H = m c = e calculated using the above equations. Figure 2 shows the magnetic eld dependences of the dissipative and Hall resistivities in the vicinity of the cyclotron resonance calculated using general relationships between the components of the conductivity and resistivity tensors. It is assumed that the microw ave power slightly exceeds the threshold of ANC. One can see that the xy vsH dependence, in contrast to the magnetic eld dependence of xx, exhibits an antisymm etrical behavior in reasonable agreement with the experimental results [18, 19] (compare with Fig.2(b) from Ref. [18] and Fig.1(c) from Ref. [19]). As seen from Fig. 2, the calculated dissipative resistivity xx is negative when H j. H . In this range of m agnetic

elds, uniform states of a 2D ES can be unstable resulting in the form ation of complex dom ain structures with the net resistance close to zero. In these calculations we put $_{\rm H} = _{\rm D} = 100$ at H = 1.5 kG and = = = 0.15. By convention the plots shown in Figs. 1 and 2 can be attributed to a A IG aA s/G aA s 2D ES with the electron mobility = 1.5 10^7 cm²/V s irradiated with m icrow aves with the frequency =2 = 50 G H z. The dependence of $_{\rm xx}$ and $_{\rm xy}$ on the m icrow ave power becomes nonlinear at its elevated values. This also leads to an alteration of the polarization dependences. How ever, this problem needs a separate study.

In sum m ary, we calculated the dependences of the dissipative and H all resistivities in 2D E S under m icrow ave radiation on them agnetic eld (its strength and sign) and the radiation polarization. We showed that m icrow ave irradiation can lead to variations of the H all resistivity which are even and odd oscillatory functions of the m agnetic eld. The obtained dependences are consistent with recent experim ental data [18, 19].

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